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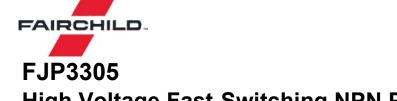
ON Semiconductor®

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October 2008



High Voltage Fast-Switching NPN Power Transistor

- High Voltage Capability
- High Switching Speed
- Suitable for Electronic Ballast and Switching Regulator



1.Base 2.Collector 3.Emitter

Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	700	V
V _{CEO}	Collector-Emitter Voltage	400	V
V _{EBO}	Emitter-Base Voltage	9	V
I _C	Collector Current (DC)	4	A
I _{CP}	Collector Current (Pulse)	8	А
I _B	Base Current	2	A
P _C	Collector Dissipation ($T_C = 25^{\circ}C$)	75	W
Tj	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-65 ~ 150	°C

Symbol	Parameter	Conditions	Min.	Тур.	Мах	Units
BV _{CBO}	Collector-Base Breakdwon Voltage	I _C = 500μA, I _E = 0	700			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C = 5mA, I _B = 0	400			V
BV _{EBO}	Emitter-Base Breakdown Voltage	I _E = 500μA, I _C = 0	9			V
I _{CBO}	Collector Cut-off Current	V _{CB} = 700V, I _E = 0			1	μA
I _{EBO}	Emitter Cut-off Current	V _{EB} = 9V, I _C = 0			1	μA
h _{FE1} h _{FE2}	DC Current Gain *	$V_{CE} = 5V, I_C = 1A$ $V_{CE} = 5V, I_C = 2A$	19 8		35 40	
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_{C} = 1A, I_{B} = 0.2A$ $I_{C} = 2A, I_{B} = 0.5A$ $I_{C} = 4A, I_{B} = 1A$			0.5 0.6 1.0	V V V
V _{BE(sat)}	Base-Emitter Saturation Voltage	$I_{C} = 1A, I_{B} = 0.2A$ $I_{C} = 2A, I_{B} = 0.5A$			1.2 1.6	V V
f _T	Current Gain Bandwidth Product	V _{CE} = 10V, I _C = 0.5A	4			MHz
C _{ob}	Output Capacitance	V _{CB} = 10V, f = 1MHz		65		pF
t _{ON}	Turn On Time	V _{CC} = 125V, I _C = 2A			0.8	μs
t _{STG}	Storge Time				4.0	μs
t _F	Fall Time				0.9	μs

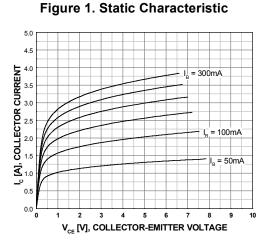
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* Pulse Test: PW $\leq 300 \mu s,$ Duty Cycle $\leq 2\%$

h_{FE} Classification

Classification	H1	H2	
h _{FE1}	19 ~ 28	26 ~ 35	

FJP3305 — High Voltage Fast-Switching NPN Power Transistor



Typical Performance Characteristics

Figure 3. DC Current Gain (O-Grade)

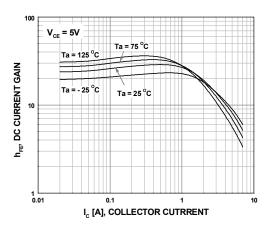


Figure 5. Saturatin Voltage (O-Grade)

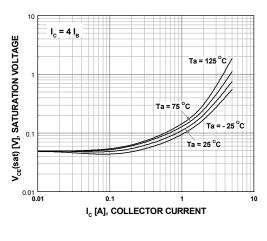


Figure 2. DC Current Gain (R-Grade)

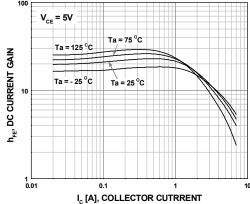


Figure 4. Saturation Voltage (R-Grade)

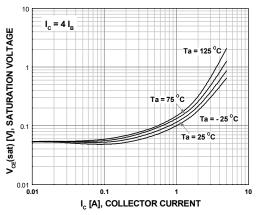
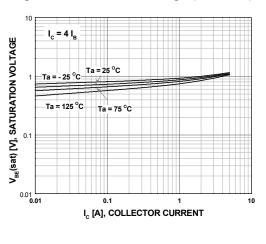
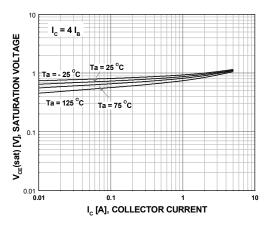


Figure 6. Saturation Voltage (R-Grade)



Typical Performance Characteristics (Continued)

Figure 7. Saturation Voltage (O-Grade)





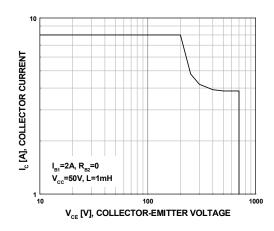
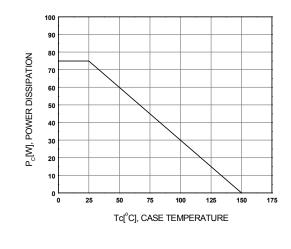
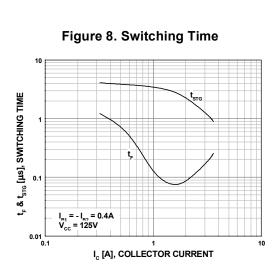
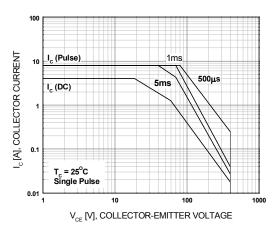


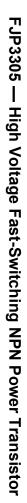
Figure 11. Power Derating













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